General Description

The WSK50P10 is the highest performance Trench P-Channel MOSFET with extreme high cell density, which provide excellent $R_{DS(ON)}$ and gate charge for most of the synchronous buck converter applications.

The WSK50P10 meet the RoHS and Green Product requirement, 100% E_{AS} guaranteed with full function reliability approved.

Features

- 100% UIS + R_g Tested.
- Reliable and Rugged
- Lead Free and Green Devices Available (RoHS Compliant)

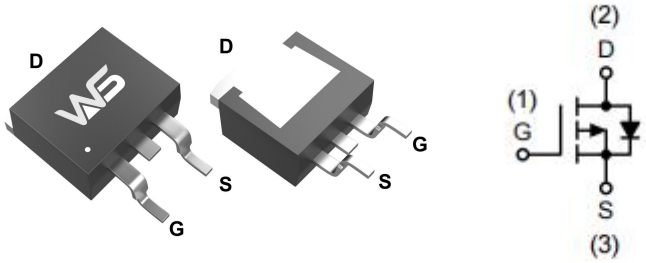
Product Summery

BV_{DSS}	$R_{DS(ON)}$	I_D
-100V	40mΩ	-50A

Applications

- Power Management for Industrial DC/DC Converters
- Load switch
- Battery protection

TO-263-2L Pin Configuration



Absolute Maximum Ratings (T_A=25°C, Unless Otherwise Noted)

Symbol	Parameter		Rating	Units
V_{DS}	Drain-Source Voltage		-100	V
V_{GS}	Gate-Source Voltage		±20	
I_D [7]	Continuous Drain Current	T_C=25°C	-50	A
		T_C=100°C	-30	
I_{DM} [3]	Pulse Drain Current		-150	
P_D [2]	Power Dissipation	T_C=25°C	140	W
I_{AS} [3]	Single pulse Avalanche Current		-35	A
E_{AS} [3]	Single pulse Avalanche Energy	L=0.3mH	87	mJ
T_{STG}	Storage Temperature Range		-55 to 150	°C
T_J	Operating Junction Temperature Range		-55 to 150	
$R_{\theta JA}$ [1,4]	Thermal Resistance-Junction to Ambient	t≤10s	20	°C/W
		Steady State	62	
$R_{\theta JC}$	Thermal Resistance-Junction to Case		1.1	

Electrical Characteristics (T_J=25°C, Unless Otherwise Noted)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS}=0V , I_D=-250μA	-100	---	---	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance	V_{GS}=-10V , I_D=-20A	---	40	52	mΩ
		V_{GS}=-4.5V , I_D=-20A	---	44	62	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	V_{GS}=V_{DS} , I_D=-250μA	-1.0	-1.6	-2.5	V
I_{DSS}	Drain-Source Leakage Current	V_{DS}=-100V , V_{GS}=0V	---	---	-1.0	μA
I_{GSS}	Gate-Source Leakage Current	V_{DS}=0V , V_{GS}=±20V	---	---	±100	nA
Q_g	Total Gate Charge (10V)	V_{DS}=-50V , V_{GS}=-10V , I_D=-5A	---	41	---	nC
Q_{gs}	Gate-Source Charge		---	8	---	
Q_{gd}	Gate-Drain Charge		---	9	---	
$T_{d(on)}$	Turn-On Delay Time	V_{DS}=-50V , V_{GS}=-10V , I_D=-5A R_L=1Ω , R_{GEN}=6Ω	---	14	---	ns
T_r	Rise Time		---	40	---	
$T_{d(off)}$	Turn-Off Delay Time		---	101	---	
T_f	Fall Time		---	106	---	
C_{iss}	Input Capacitance	V_{DS}=-50V , V_{GS}=0V , f=1.0MHz	---	2130	---	pF
C_{oss}	Output Capacitance		---	195	---	
C_{rss}	Reverse Transfer Capacitance		---	15	---	

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
I_S [7]	Continuous Source Current		---	---	-50	A
V_{SD}	Diode Forward Voltage	V_{GS}=0V , I_S=-1A	---	-0.7	-1.2	V
t_{rr}	Reverse Recovery Time	I_F=-20A , di/dt=500A/μs	---	104	---	ns
Q_{rr}	Reverse Recovery Charge		---	280	---	nC

Note:

1. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C. The Power dissipation P_{DSM} is based on $R_{\theta JA}$ t≤ 10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
2. The power dissipation P_D is based on $T_{J(MAX)}$=150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
3. Single pulse width limited by junction temperature $T_{J(MAX)}$=150°C.
4. The $R_{\theta JA}$ is the sum of the thermal impedance from junction to case $R_{\theta JC}$ and case to ambient.
5. The static characteristics in Figures 1 to 6 are obtained using <300μs pulses, duty cycle 0.5% max.
6. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of $T_{J(MAX)}$=150°C. The SOA curve provides a single pulse rating.
7. The maximum current rating is package limited.
8. These tests are performed with the device mounted on 1 in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C.
9. The maximum current rating is silicon limited

Typical Characteristics

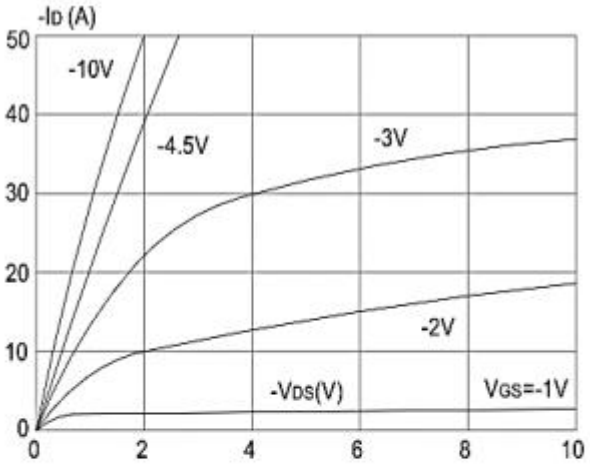


Figure1: Output Characteristics

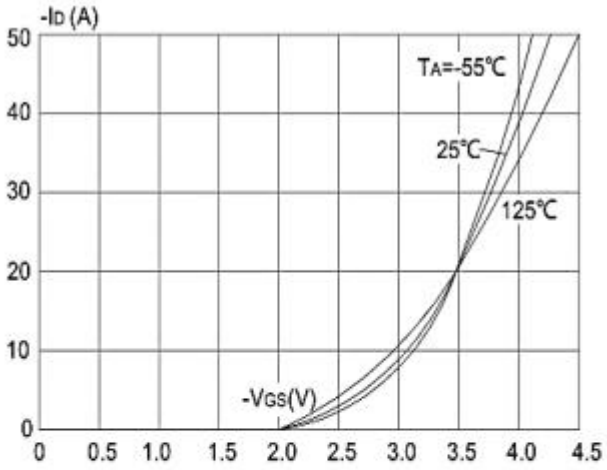


Figure 2: Typical Transfer Characteristics

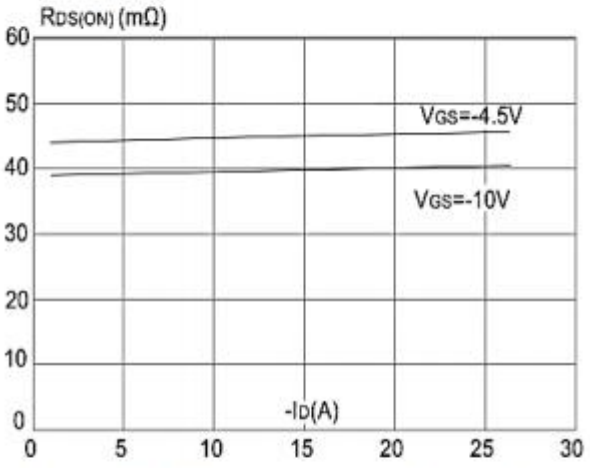


Figure 3:On-resistance vs. Drain Current

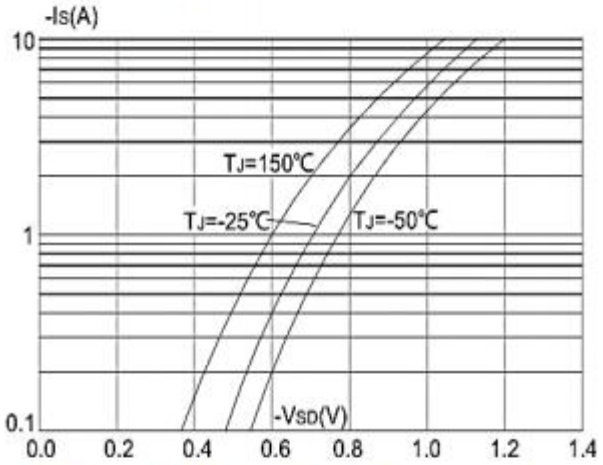


Figure 4: Body Diode Characteristics

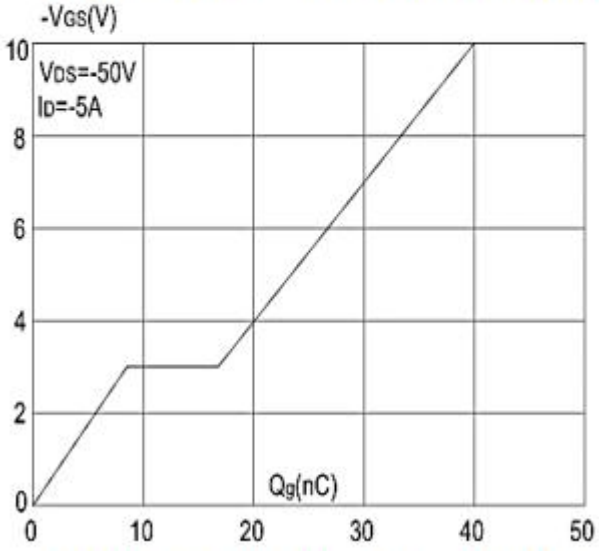


Figure 5: Gate Charge Characteristics

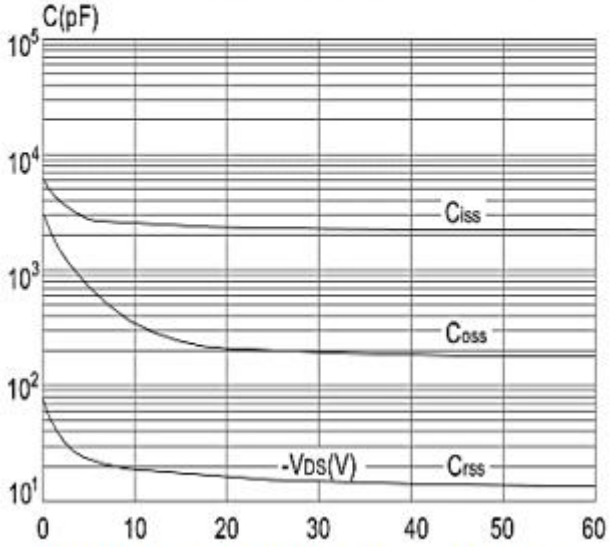


Figure 6: Capacitance Characteristics

Typical Characteristics (Cont.)

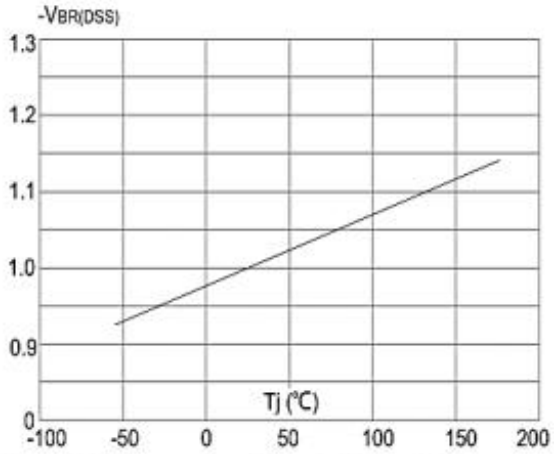


Figure 7: Normalized Breakdown Voltage vs Junction Temperature

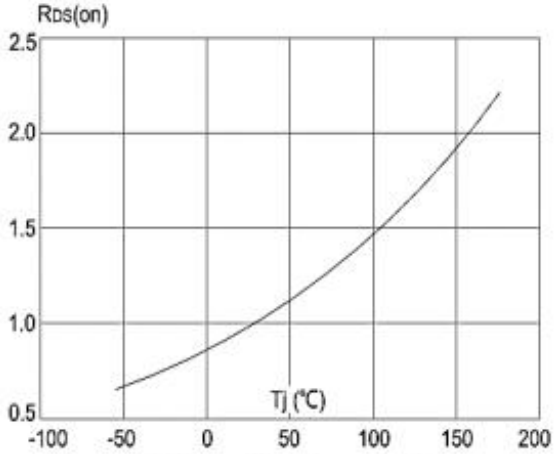


Figure 8: Normalized on Resistance vs. Junction Temperature

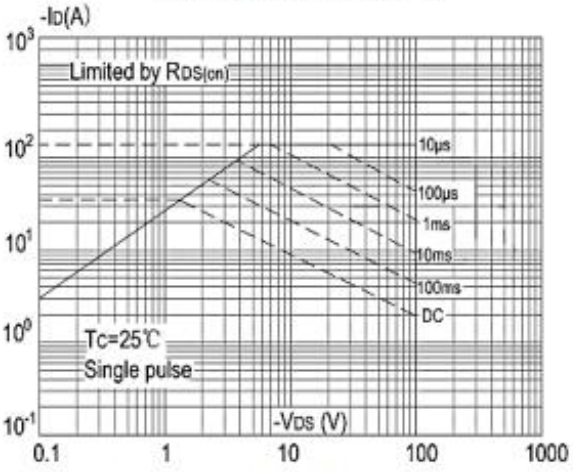


Figure 9: Maximum Safe Operating Area

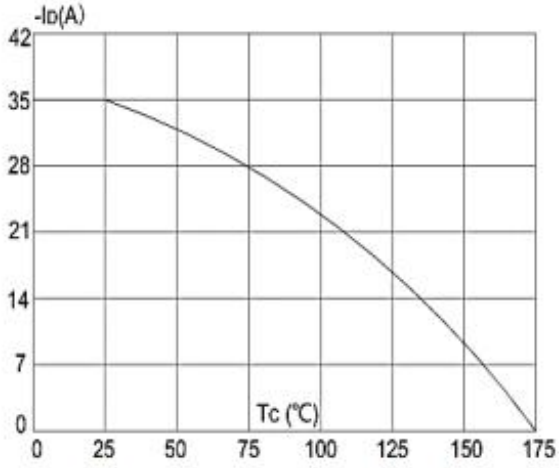


Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature

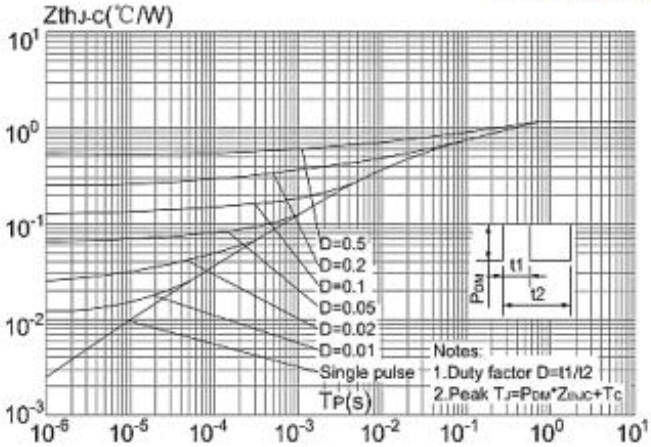
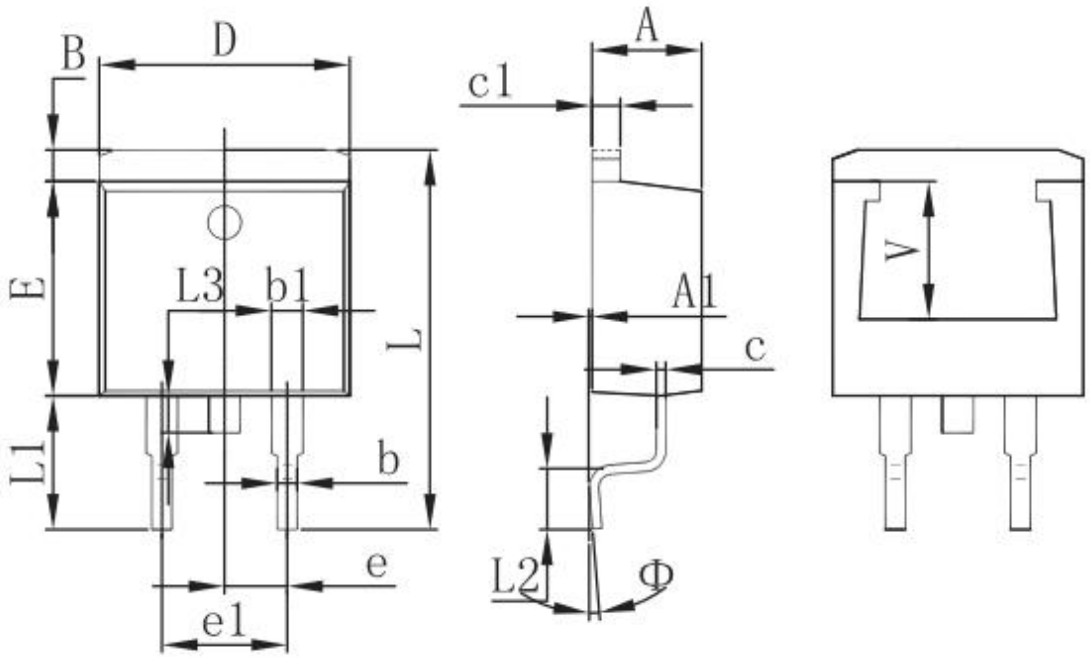


Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambien

Packaging information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.470	4.670	0.176	0.184
A1	0.000	0.150	0.000	0.006
B	1.120	1.420	0.044	0.056
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
e	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
L	14.940	15.500	0.588	0.610
L1	4.950	5.450	0.195	0.215
L2	2.340	2.740	0.092	0.108
L3	1.300	1.700	0.051	0.067
Φ	0°	8°	0°	8°
V	5.600 REF.		0.220REF.	

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